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A stable and true-blue emissive hexacoordinate Si(IV) N-heterocyclic carbene complex and its use in organic light-emitting diodes†

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A neutral hexacoordinate Si(IV) complex containing two tridentate N-heterocyclic carbene ligands is synthesised and characterized by X-ray crystallography, optical spectroscopy, electrochemistry and computational methods. The stable compound exhibits remarkable deep-blue photoluminescence particularly in the solid state, which enables its use as an electroluminescent material in organic light-emitting diodes.

Introduction

Organosilicon compounds are an interesting class of photo-functional species with appealing application as electroluminescent and electron transport materials as well as photo-dynamic therapy agents.¹ Selected examples are displayed in Chart 1. The majority of organosilicon derivatives are conjugated molecules that contain Si–C bond(s), and their unique optoelectronic properties have been reported to date.^{2–5} Hypercoordinated Si derivatives for such applications are much less explored. An interesting example is based on Si(IV) phthalocyanines where the tetracoordinated macrocycle helps stabilize the otherwise labile Si–N bonds.⁶ Little efforts have been devoted to the stabilization of silicon complexes using chelating bi- and/or tridentate architectures with C–Si, O–Si and N–Si bonds. Tetracoordinate N–Si complexes containing 1,2-bis(indol-2-yl)benzene have shown blue photoluminescence with high efficiency.⁷ Dipyrromethene moieties

have been used to form tetracoordinated Si complexes^{8,9} and adjacent hydroxy anchors gave pentacoordinate O[−]N[−]N[−]O complexes with efficient red and near-IR luminescence.^{10,11} More recently, hexacoordinate N–Si complexes featuring two 2,6-bis(benzimidazol-2-yl)pyridine *pincer*-type ligands have been prepared and their excellent optoelectronic properties and thermal stability have enabled their use in Organic Light-Emitting Diodes (OLEDs) and photovoltaic devices.^{12,13} Silicon remains very attractive as a tetravalent, earth-abundant, non-

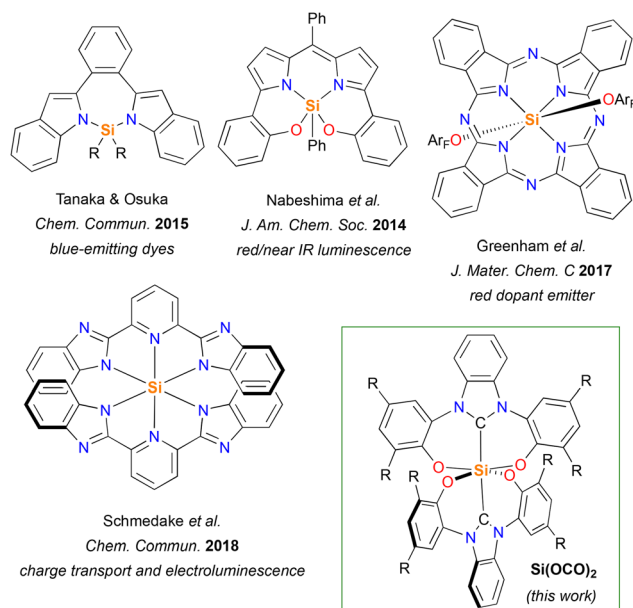


Chart 1 Selected examples of tetra-, penta- and hexacoordinate Si complexes with remarkable photophysical properties and the molecular structure of the Si(OCO)₂ complex.

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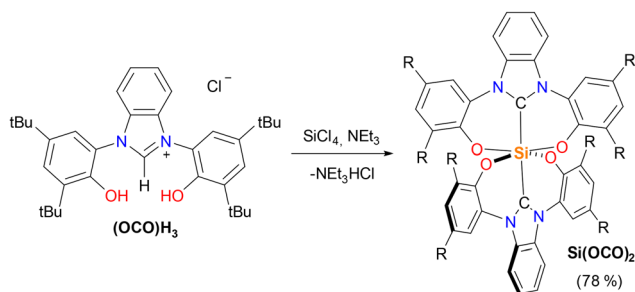
toxic lightweight atom and it often has significant influence on the optical and electronic properties. On the other hand, there is currently great interest in developing stable deep-blue emitters for light-emitting devices. Despite these promising recent examples, the coordination chemistry of Si(IV) chelates is still overlooked most likely due to their supposed instability.

N-Heterocyclic carbenes (NHCs) have been recognised as privileged ligands in organometallic chemistry of transition metals^{15–17} and to provide robust (electro)luminescent materials for optoelectronics.^{18,19} Interestingly, the use of NHCs to stabilize Si(IV) is gaining increasing attention.¹⁴ Although NHCs can stabilize low valence states and induce new reactivities,^{20–24} they have been mostly used with halogenated Si(IV) reagents to exploit hypervalent pentacoordinate Si(IV) intermediates and, more recently, to stabilize less common Si(IV) alkoxysilanes with highly electronegative bis-trifluoroalkoxy ligands. Pentacoordinate NHC–Si intermediates have been postulated to account for the stability of free NHC carbenes in silicones as well.²⁵

A few years ago we introduced a new family of LX₂ pincer-type NHC ligands with the O[^]C[^]O motif, namely (OCO)H₃, characterised by a central imidazolylidene NHC moiety with two lateral chelating phenolic groups (see Scheme 1).^{26,27} This ligand has proven to be very versatile and robust for coordinating oxophilic metals with high oxidation states such as Ti(IV), Zr(IV) and Hf(IV).^{28–32} Herein, we report the synthesis and comprehensive characterization of a homoleptic, neutral, hexacoordinate luminescent complex, namely Si(OCO)₂, which displays high thermal and photo-stability in solution and in the solid state under air and moisture. The optical properties are investigated and elucidated also with the help of computational approaches. Finally, proof-of-concept OLED devices are successfully fabricated, and the electroluminescence performances are described.

Results and discussion

The complex Si(OCO)₂ was straightforwardly synthesized from SiCl₄ and the corresponding benzimidazolium precursor (OCO)H₃ resulting in a robust and air stable compound that can be easily purified by column chromatography (Scheme 1



Scheme 1 Synthetic pathway used for the preparation of complex Si(OCO)₂. R = *tert*-butyl.

and the ESI for experimental details†).³³ NMR data are reported in Fig. S1–S3 of the ESI.† The ¹H NMR spectrum displays a highly symmetric resonance pattern consistent with an average D_{2d} symmetry of the molecule, expectedly, as shown in Fig. S1 in the ESI.† ²⁹Si NMR spectroscopy confirms the hexacoordinate nature of the silicon with a δ = –197.4 ppm (Fig. S3†), a chemical shift in the same range as the hexacoordinated complex reported by Schmedake and coworkers which displays a δ = –186 ppm (see Chart 1).¹²

Single crystals suitable for X-ray investigation were obtained and the structure is displayed in Fig. 1 and S4.† Crystallographic refinement parameters are listed in Table S1 of the ESI.† In the crystal structure, the silicon center adopts an octahedral geometry with C_{NHC} atoms located mutually in the *trans* geometry. The Si–O distances are long with an average bond length *d*(Si–O) = 1.78 Å, typical for a hypervalent silicon, and the *d*(Si–C_{NHC}) = 1.90 Å. The phenolates are outside the plane formed by the carbene heterocycle with an average angle of *ca.* 41° between the two phenolate planes of the ligand, with an O–Si–O angle of 174.7°. Interestingly, the Si(OCO)₂ complex displays a very high thermal stability as demonstrated by thermogravimetric analysis where degradation starts above 200 °C with the 5% weight loss temperature *T*_{5%} as high as 352 °C (Fig. S5†). Cyclic voltammetry was employed to assess the electrochemical behavior of Si(OCO)₂ in CH₂Cl₂ solution. At negative potentials it presents an irreversible reduction process *R*₁ at –2.30 V vs. Fc|Fc⁺, which is assigned to the reduction of the ligand (see Fig. S6 and Table S2 in the ESI†).

Density Functional Theory (DFT) computations were performed on a species analogous to Si(OCO)₂ in which the *tert*-butyl substituents on the phenyl rings have been replaced with

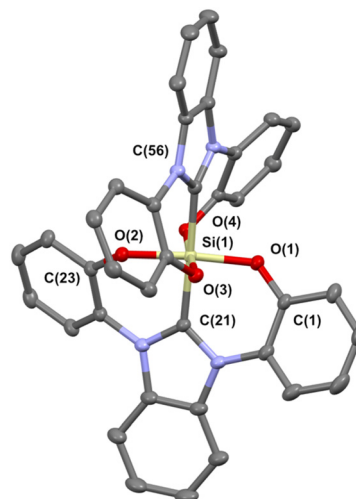


Fig. 1 Molecular structure of Si(OCO)₂ (CCDC 2284375). The *t*Bu groups and H atoms are omitted for clarity. Selected bond lengths [Å] and angles [°]: Si(1)–O(1), 1.7707(15); Si(1)–O(4), 1.7709(15); Si(1)–O(3), 1.7849(15); Si(1)–O(2), 1.7865(15); Si(1)–C(56), 1.904(2); Si(1)–C(21) 1.909(2); O(1)–Si(1)–O(4), 89.80(7); O(1)–Si(1)–O(3), 89.67(7); O(4)–Si(1)–O(3), 174.50(7); O(1)–Si(1)–O(2), 174.84(7).



methyl groups, namely $\text{Si}(\text{O}^{\text{Me}}\text{CO}^{\text{Me}})_2$. The optimized geometry of the latter complex in its ground state shows an exact S_4 symmetry. Molecular orbitals (MOs) closer to the frontier region are displayed in Fig. 2, whereas a larger set of MO density surfaces is reported in Fig. S9,† together with their symmetry and energy.

The eight higher-energy filled orbitals are located on the four phenolate moieties. They are various combinations (of a, b and e symmetry) of the p orbitals of the oxygen atoms with two of the π orbitals of the phenyl groups (corresponding to the e_{1g} degenerate bonding orbitals of benzene). The first four lower unoccupied molecular orbitals are located on the two NHC moieties. The degenerate LUMOs of e symmetry have contribution mainly from the five-membered rings while the next two orbitals (of a and b symmetry) have contribution mainly from the six-membered rings. The following two degenerate orbitals are somehow delocalized all over the molecule. No significant contribution from the silicon atom can be found in any of the orbitals described.

The experimental electronic absorption and emission spectra recorded for $\text{Si}(\text{OCO})_2$ and the comparison with those of the pro-ligand $(\text{OCO})\text{H}_3$ are displayed in Fig. 3 and the data are summarized in Table 1. For dilute CH_2Cl_2 samples (2×10^{-5} M), the UV-Vis spectrum of $\text{Si}(\text{OCO})_2$ displays three main regions of absorption with a broad profile. The two bands at lower energy, $\lambda_{\text{abs}} = 332$ and 299 nm, display lower intensity, with $\epsilon = 1.3 \times 10^4$ and $1.5 \times 10^4 \text{ M}^{-1} \text{ cm}^{-1}$, respectively. A more intense band is present with a maximum at $\lambda_{\text{abs}} = 271$ nm ($\epsilon = 2.2 \times 10^4 \text{ M}^{-1} \text{ cm}^{-1}$).

Time-dependent DFT (TD-DFT) supported the photo-physical characterization. Given the composition of the HOMOs and LUMOs, all the transitions up to ca. 4.95 eV (corresponding to ca. 250 nm) are mainly intraligand charge transfer ($^1\text{ILCT}$) transitions, characterized by a large electron density displacement (ca. 0.25–0.45 e^-) from the phenolate moieties to the NHC rings. In particular, the transitions computed at 348 nm (S_1 and S_2 , of E symmetry), 309 nm (S_8), and 280 nm (S_{12}) involve both the NCN atoms and the annulated

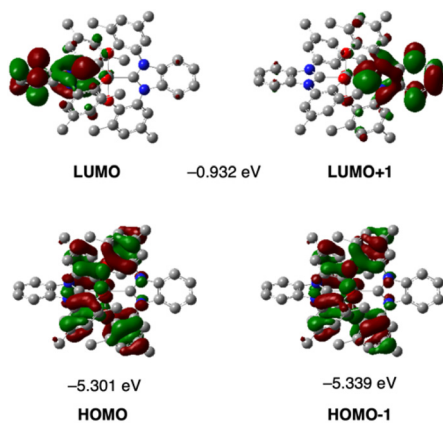


Fig. 2 MO isodensity surfaces of HOMO–1 to LUMO+1 computed for compound $\text{Si}(\text{O}^{\text{Me}}\text{CO}^{\text{Me}})_2$.

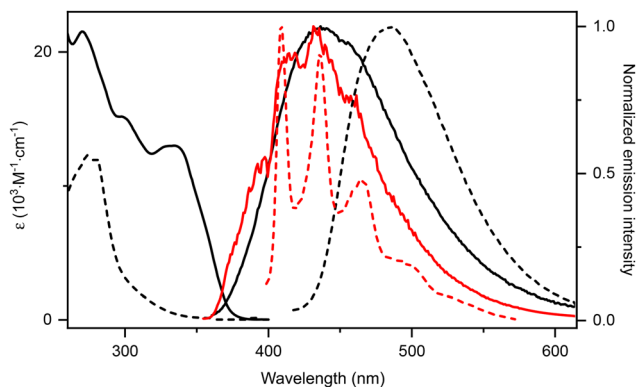


Fig. 3 UV-vis absorption and photoluminescence emission in dilute CH_2Cl_2 (2×10^{-5} M) (black traces) and in a 2-MeTHF glassy matrix at 77 K (red traces) for complex $\text{Si}(\text{OCO})_2$ (solid traces) and pro-ligand $(\text{OCO})\text{H}_3$ (dashed traces). Emission spectra were recorded upon excitation at $\lambda_{\text{exc}} = 320$ and 360 nm for $\text{Si}(\text{OCO})_2$ and $(\text{OCO})\text{H}_3$, respectively.

ring of the NHC moiety, while the transitions computed at 283 nm (S_9 and S_{10} , of E symmetry) and 274 nm (S_{13} and S_{14} , of E symmetry) involve the six-membered ring only. All the degenerate transitions correspond to transfer of electrons within a single ligand with $\pi_{\text{Oph}} \rightarrow \pi^*_{\text{NHC}}$ nature. In addition, transitions S_9 , S_{10} and S_{12} involve excitations in orbitals delocalized also on the OPh groups, assuming a partial $\pi_{\text{Oph}} \rightarrow \pi^*_{\text{Oph}}$ character. Data for all the described transitions are reported in Table S3.†

In the experimental absorption of pro-ligand $(\text{OCO})\text{H}_3$ only the band at $\lambda_{\text{abs}} = \text{ca. } 270$ nm is present with about half of the intensity compared to that observed for $\text{Si}(\text{OCO})_2$, supporting these attributions. Additionally, a more intense ($\epsilon = 5.5 \times 10^4 \text{ M}^{-1} \text{ cm}^{-1}$) band is clearly visible at $\lambda_{\text{abs}} = 245$ nm in solvents of larger optical transparency window (e.g. THF) which can be ascribed with confidence to singlet-manifold $^1\pi \rightarrow \pi^*$ processes mainly involving the NHC scaffold (Fig. S7†). A minor solvent effect is observed for the lower energy band at $\lambda_{\text{abs}} = \text{ca. } 340$ nm which shifts bathochromically by ca. 440 cm^{-1} upon decreasing solvent polarity in the order $\text{MeOH} \rightarrow \text{CH}_2\text{Cl}_2 \rightarrow \text{THF} \rightarrow \text{toluene}$. Despite the overall CT character of the transitions, small solvatochromism is observed since these excitation processes involve both the $\text{O}_{\text{PhO}}\text{C}_{\text{NHC}}\text{O}_{\text{PhO}}$ chromophoric scaffolds with an overall spherically symmetric redistribution of the electron-hole pair density at Franck–Condon.

Upon photoexcitation in the lower-energy band, samples of $\text{Si}(\text{OCO})_2$ in CH_2Cl_2 display deep-blue emission with a broad and structureless profile peaking at $\lambda_{\text{em}} = 437$ nm with a photoluminescence quantum yield (PLQY) of 2% (Fig. 3 and Table 1). This emission arises from a short-lived excited state $\tau = 209$ ps, insensitive to oxygen quenching. The high radiative rate constant (k_r) for this process ($k_r = 9.6 \times 10^7 \text{ s}^{-1}$) is characteristic of a strongly allowed transition originating from a singlet manifold. On the other hand, the non-radiative rate constant (k_{nr}) was as high as $4.9.6 \times 10^9 \text{ s}^{-1}$, indicative of the presence of efficient quenching channels coupling with the emitting excited state. The quenching is attributable to the



Table 1 Photophysical properties of Si(OCO)₂ and (OCO)H₃ in a dilute air-equilibrated CH₂Cl₂ solution (2.0 × 10⁻⁵ M) at room temperature, in a 2-MeTHF glassy matrix at 77 K and in the solid state as crystalline powder. Radiative and non-radiative rate constants were determined with the equations $k_r = \text{PLQY}/\tau$ and $k_{nr} = (1 - \text{PLQY})/\tau$, respectively. sh denotes a shoulder

	$\lambda_{\text{max}}(\epsilon)$ [nm, (10 ³ M ⁻¹ cm ⁻¹)]	λ_{em} [nm]	PLQY (%)	τ_{obs} [ns]	k_r [10 ⁷ s ⁻¹]	k_{nr} [10 ⁸ s ⁻¹]	λ_{em} [nm]	PLQY (%)	τ_{obs} [ns]	k_r [10 ⁷ s ⁻¹]	k_{nr} [10 ⁷ s ⁻¹]	λ_{em} [nm]	τ_{obs} [ns]	τ_{obs} [ns]
	CH ₂ Cl ₂ , 2 × 10 ⁻⁵ M, air-equilibrated	air-equilibrated					Crystalline solid					77 K, 2-MeTHF		
(OCO)	274 (12.25), 280 (12.01)	485	1	1.87	0.5	5.3	434	1	5.7 (38%), 1.81 (62%)	0.23	22.6	410, 436, 467, 500sh	1.75 (34%), 1.11 (64%)	1.58
H ₃	271 (21.55), 299sh (15.02), 332 (12.88)	437, 456sh	2	0.21	9.6	46.9	418	32	2.98	10.7	22.8	414, 433, 462sh	1.35 (25%), 5.60 (75%)	4.31

rotational motion of the *tert*-butyl substituents, the fluxional twisting motion of the two PhO–Si–OPh moieties and the large geometrical distortion occurring in the S₁ (Table S3†). The emission S₁ → S₀ is computed at 481/394 nm (vertical/adiabatic). The large difference between the S₀ and S₁ geometries is responsible for the significant difference between the two computed values. The corresponding electron density-difference map shows the expected electron transfer from the NHC moiety to the OPh groups (*ca.* 0.40 e⁻, see Fig. 4).

Emission spectra appear to be slightly influenced by the solvent with an overall shift by about 926 cm⁻¹ from MeOH to CH₂Cl₂ (Fig. S7†). An increase of the PLQY up to 4% is also observed in MeOH and toluene samples along with a prolongation of the excited state lifetime (Table S3†). Solvent polarity is likely not the only parameter affecting the emission solvatochromism of this compound: specific solvent–solute interactions are expected to be at play as well. As a consequence, being based on a polarizable continuum model, TD-DFT results only qualitatively agree with the observed shift due to solvent effects (Table S6†).

Photophysical measurements of Si(OCO)₂ carried out in a 2-MeTHF glassy matrix at 77 K yield a slightly structured emission profile with a minor hypsochromic shift compared to the emission in fluid THF and a few ns-scale lifetime, indicative of a partial ¹CT character. On the other hand, for (OCO)H₃ the spectrum at 77 K becomes highly structured and shows a larger hypsochromic shift, supporting the sizeable ¹CT character of the excited state in the cationic pro-ligand (see Fig. 3).

Remarkably, spin-coated thin film samples of Si(OCO)₂ at 10 wt% doping level in polymer matrices such as poly-methyl-methacrylate (PMMA) and polystyrene (PS) switch-on the emission properties of the samples as a consequence of the rigidification of the environment and restriction of the rotovibrational freedom of the emitters. Indeed, doped thin films display intense, structureless, deep-blue photoluminescence with maxima at $\lambda_{\text{em}} = 419$ and 422 nm, and PLQYs as high as 28% and 32%, respectively (Fig. S8† and Table 2), with the CIE_y coordinate as low as 0.11, making Si(OCO)₂ of great potential interest for the fabrication of deep-blue OLED

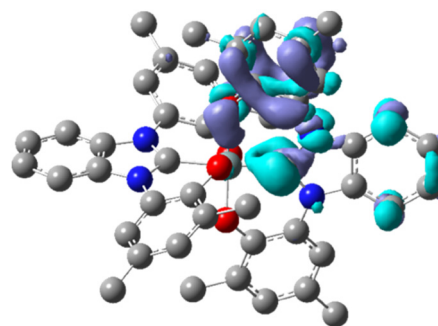


Fig. 4 Electronic density-difference map computed (at the optimized S₁ geometry) for the vertical transition S₁ → S₀ of the methyl-substituted analogue of Si(OCO)₂. Cyan and violet colours indicate a decrease and increase in electron density, respectively.



Table 2 Photophysical properties of Si(OCO)₂ spin-coated thin films

Compound	Doping % polymer	λ_{em} [nm]	PLQY (%)	CIE (x, y)	τ_{obs} [ns]	$\bar{\tau}_{\text{obs}}$ [ns]
Si(OCO) ₂	10% PMMA 120k	419	28	0.17, 0.11	1.75 (30%) 4.43 (62%)	4.01
	10% PS 35k	420	32	0.17, 0.11	2.94 (64%) 5.08 (36%)	3.98

devices. Interestingly, crystalline samples of Si(OCO)₂ show a narrower emission profile at $\lambda_{\text{em}} = 418$ nm due to the even more rigid environment provided by the dense crystal packing with a PLQY of 32%. The (OCO)H₃ derivative, on the other hand, shows a low PLQY of 1% and red-shifted emission at $\lambda_{\text{em}} = 434$ nm in the solid state. For both species, this emission is ascribed to an excited state with ¹ILCT (¹ $\pi_{\text{PhO}} \rightarrow \pi_{\text{NHC}}^*$, S₁ → S₀) character.

Owing to its interesting photophysical properties, the Si(OCO)₂ complex was employed as an emitter in vacuum-processed OLED devices to explore its potential as an electroluminescent material under various doping concentrations between 8 and 20 wt%. The device performances in terms of electroluminescence (EL) spectra, current density–voltage–luminescence (*J–V–L*), external quantum efficiency (EQE) vs. luminance and luminance efficiency vs. luminance are displayed in Fig. 5. The corresponding details and additional characteristics of the fabricated OLEDs are provided in Fig. S10 and Table S7 of the ESI.† The optimized architecture for the tested devices was as follows: ITO (120 nm)/TAPC:MoO₃ 20 wt% (5 nm)/TAPC (25 nm)/TCTA (10 nm)/mCP:Si(OCO)₂ (20 nm)/TmPyPB (50 nm)/LiF (0.8 nm)/Al (120 nm), where TAPC is 1,1-bis[(di-4-tolylamino)phenyl]cyclohexane, TCTA is 4,4',4''-tris(carbazol-9-yl)-triphenylamine, mCP is *N,N'*-dicarbazolyl-3,5-benzene and TmPyPB is 1,3,5-tri[(3-pyridyl)-phen-3-yl]benzene.

The OLED devices fabricated by embedding the complex Si(OCO)₂ in the electroluminescent layer showed featureless and relatively narrow EL spectra peaking at $\lambda_{\text{EL,max}} = 408$ –423 nm depending on the doping concentration in the investigated range. The EL spectra largely resembled the profile observed in the photoluminescence measurements of doped thin films at 10 wt% doping level in either the PMMA or PS polymer matrix (see above). This is indicative of the fact that the same excited state is involved in both photo- and electro-generated luminescence processes. Optimized devices displayed adequate EL performance with a peak EQE of 1.3% (0.8 cd A⁻¹), maximum luminance value of 2566 cd m⁻² and saturated true-blue emission. Notably, the tested devices with varying doping concentrations showed similar EL performances, including the current density, luminance, efficiency, and spectrum, highlighting that Si(OCO)₂ is insensitive to the doping level.

Conclusions

In conclusion, we have synthesized and characterized a neutral hexacoordinate Si(IV) complex containing two tridentate *N*-heterocyclic carbene ligands. Our studies included X-ray crystallography, optical spectroscopy, electrochemistry and computational methods. The homoleptic complex exhibits remarkable dark-blue photoluminescence, particularly in the solid state, enabling it to be used as an electroluminescent material in organic light-emitting diodes. This study demonstrates the benefits of combining silicon and carbenes for achieving a novel class of stable emitters based on the Si(IV)–NHC core and suitable as true-blue EL materials in OLED devices for the first time.

Experimental details

General experimental remarks and details including the synthesis, X-ray crystallographic analysis, NMR spectroscopy, photophysical, electrochemical, and computational characterisation as well as OLED device fabrication can be found in the ESI† section along with the additional data.

Conflicts of interest

There are no conflicts to declare.

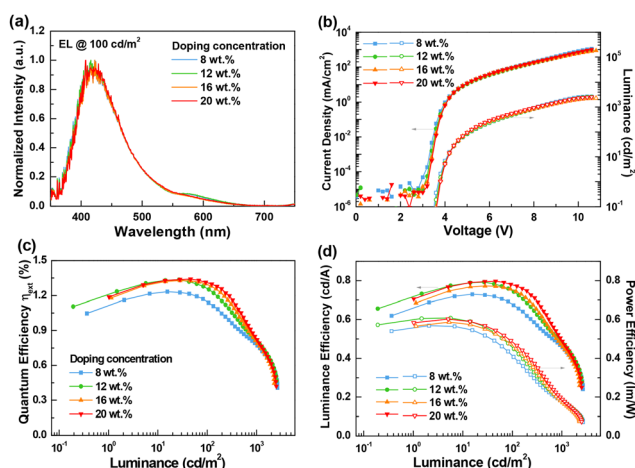


Fig. 5 (a) Normalized EL spectra at a luminance of 100 cd m⁻²; (b) current density–voltage–luminescence (*J–V–L*) characteristics of OLED devices with different doping concentrations; (c) external quantum efficiency vs. luminance; (d) luminance/power efficiency vs. luminance for the devices with different doping concentrations.



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